

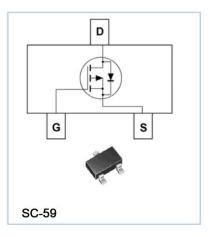


P-Channel Enhancement Mode MOSFET Feature

• -16V/-4A, $R_{DS(ON)} = 90m \Omega (MAX)$ @VGS = -4.5V.

 $R_{DS(ON)} = 130 m \Omega (MAX)$ @VGS = -2.5V.

- Super High dense cell design for extremely low RDS(ON)
- Reliable and Rugged
- SC-59 for Surface Mount Package



Applications

Power Management

Portable Equipment and Battery Powered Systems.

Absolute Maximum Ratings

TA=25°C Unless Otherwise noted

Parameter	Symbol	Limit	Units
Drain-Source Voltage	V _{DS}	-16	v
Gate-Source Voltage	V _{GS}	± 8	v
Drain Current-Continuous	ID	-4	А

Electrical Characteristics

T_A=25℃ Unless Otherwise noted

Parameter	Symbol	Test Conditions	Min	Тур.	Max	Units
Off Characteristics						
Drain to Source Breakdown Voltage	BVDSS	VGS=0V, ID=-250µA	-16		-	v
Zero-Gate Voltage Drain Current	IDSS	VDS=-12V, VGS=0V	-	-	-1	μΑ
Gate Body Leakage Current, Forward	IGSSF	VGS=8V, VDS=0V	-	-	100	nA
Gate Body Leakage Current, Reverse	IGSSR	VGS=-8V, VDS=0V	-	-	-100	nA
On Characteristics						
Gate Threshold Voltage	VGS(th)	VGS= VDS, ID=-250µA	-0.5		-1.5	v
Static Drain-source	BD5/OND	VGS =-4.5V, ID =-4.0A	-	-	90	mΩ
On-Resistance	RDS(ON)	VGS =-2.5V, ID =-2.0A	-	-	130	mΩ
Drain-Source Diode Characterist	ics and Maxin	num Ratings				
Drain-Source Diode Forward Voltage	VSD	VGS =0V, IS=-1.25A			-1.2	v

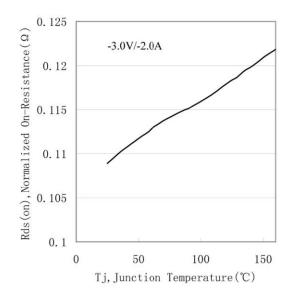
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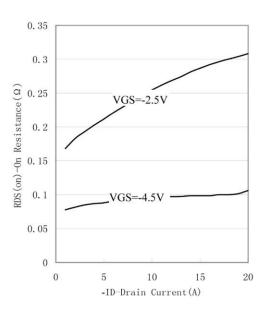






Typical Characteristics





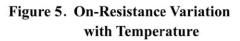


Figure 6. On-Resistance vs. Drain Current

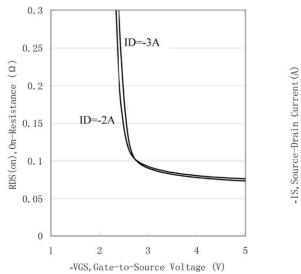


Figure 7. On-Resistance vs. Gate-to-Source Voltage

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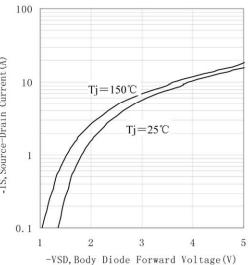


Figure 8. Source-Drain Diode Forward Voltage





SK2307A

Typical Characteristics

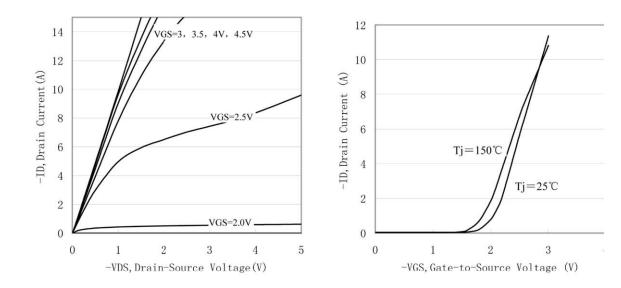


Figure 1. Output Characteristics

Figure 2. Transfer Characteristics

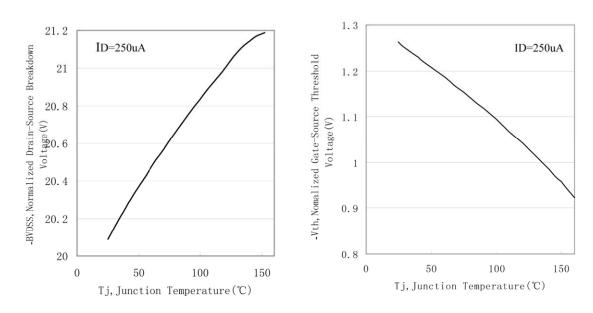


Figure 3. Breakdown Voltage Variation with Temperature

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Figure 4. Gate Threshold Variation with Temperature



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